## **PROCEEDINGS OF SPIE**

# High-Power Diode Laser Technology XVIII

Mark S. Zediker Editor

2–4 February 2020 San Francisco, California, United States

Sponsored and Published by SPIE

Volume 11262

Proceedings of SPIE 0277-786X, V. 11262

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ISSN: 0277-786X ISSN: 1996-756X (electronic)

ISBN: 9781510632875 ISBN: 9781510632882 (electronic)

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